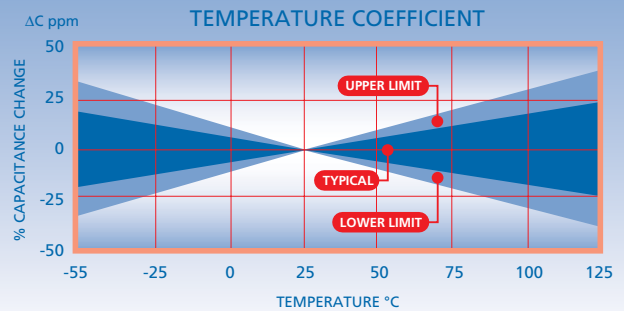




Dielectric Characteristics

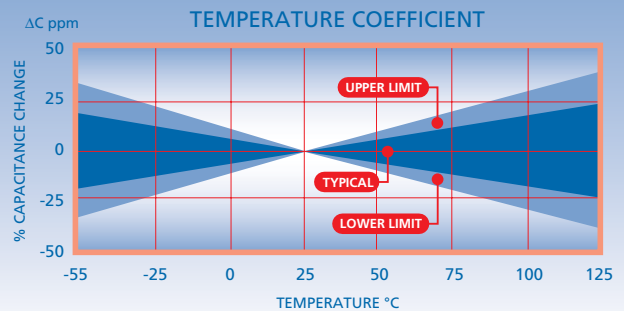
COG/NP0 (N) Ultra Stable and RoHS 2013 (RN) type

Operating temperature range:	-55°C to 125°C
Temperature coefficient:	0 ±30 ppm/°C
Dissipation factor:	0.1% max @ 25°C
Insulation resistance	@25°C: >100GΩ or >1000ΩF whichever is less @125°C: >10GΩ or >100ΩF whichever is less
Dielectric withstanding voltage	<200V: 250% 201-500V: 150% or 500V whichever is greater >500V: 120% or 750V whichever is greater
Ageing rate:	0% per decade
Test parameters:	1KHz, 1.0 ±0.2 VRMS, 25°C 1MHz for Capacitance ≤100pF



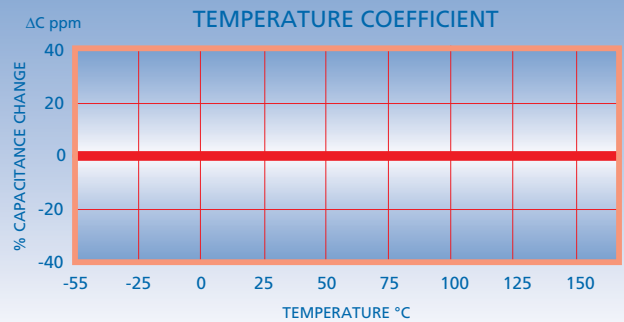
COG/NP0 (M) Ultra Stable Non Magnetic

Operating temperature range:	-55°C to 125°C
Temperature coefficient:	0 ±30 ppm/°C
Dissipation factor:	0.1% max @ 25°C
Insulation resistance	@25°C: >1000ΩF or >10000ΩF whichever is less @125°C: >100ΩF or >1000ΩF whichever is less
Dielectric withstanding voltage	<200V: 250% 201-500V: 150% or 500V whichever is greater >500V: 120% or 750V whichever is greater
Ageing rate:	0% per decade
Test parameters:	1KHz, 1.0 ±0.2 VRMS, 25°C 1MHz for Capacitance ≤100pF



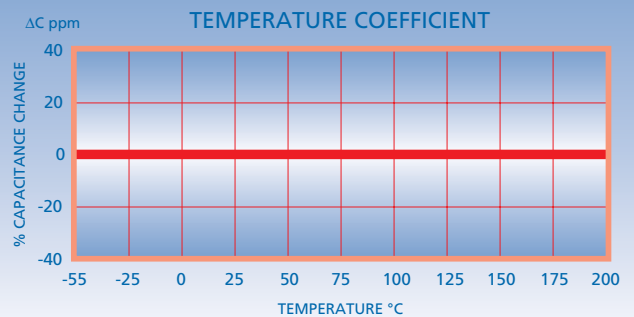
COG/NP0 (F) Ultra Stable High Temperature (up to 160°C)

Operating temperature range:	-55°C to 160°C
Temperature coefficient:	0 ±30 ppm/°C
Dissipation factor:	0.1% max @ 25°C
Insulation resistance	@25°C: >100GΩ or >1000ΩF whichever is less @160°C: >1GΩ or >10ΩF whichever is less
Dielectric withstanding voltage	<200V: 250% 201-500V: 150% or 500V whichever is greater >500V: 120% or 750V whichever is greater
Ageing rate:	0% per decade
Test parameters:	1KHz, 1.0 ±0.2 VRMS, 25°C 1MHz for Capacitance ≤100pF

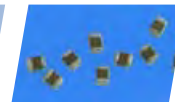


COG/NP0 (D) Ultra Stable High Temperature (up to 200°C)

Operating temperature range:	-55°C to 200°C
Temp. coefficient ≤200°C:	0 ±30 ppm/°C
Dissipation factor @ 25°C:	0.1% Max.
Insulation resistance	@25°C: >100GΩ or >1000ΩF whichever is less @200°C: >1GΩ or >10ΩF whichever is less
Dielectric withstanding voltage	<200V: 250% 201-500V: 150% or 500V whichever is greater >500V: 120% or 750V whichever is greater
Ageing rate:	0% per decade
Test parameters:	1KHz, 1.0 ±0.2 VRMS, 25°C 1MHz for capacitance ≤100pF

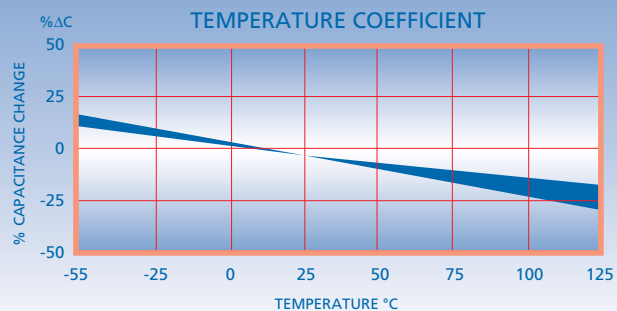


Dielectric Characteristics



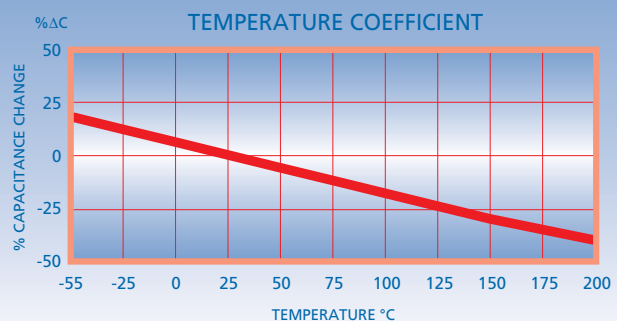
R3L (K) Ultra Stable

Operating temperature range:	-55°C to 125°C
Temperature coefficient:	-2200 ±500 ppm/°C
Dissipation factor:	0.1% max @ 25°C
Insulation resistance	@25°C: >1000ΩF or >10000ΩF whichever is less @125°C: >100ΩF or >1000ΩF whichever is less
Dielectric withstanding voltage	≤200V: 250% 201-500V: 150% or 500V whichever is greater >500V: 120% or 750V whichever is greater
Ageing rate:	0% per decade
Test parameters:	1KHz, 1.0 ±0.2 VRMS, 25°C 1MHz for Capacitance ≤100pF



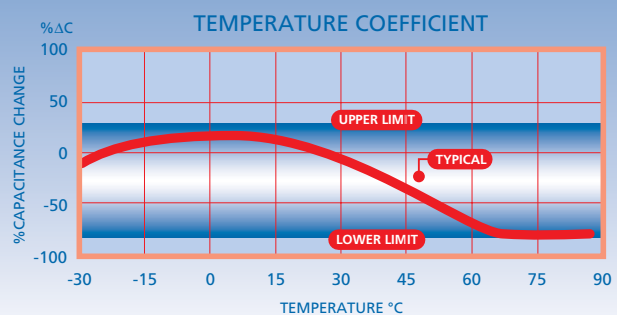
R2D (R) Pulse Energy

Operating temperature range:	-55°C to 200°C
Temperature coefficient:	-2200 ±500 ppm/°C
Dissipation factor:	0.1% max @ 25°C
Insulation resistance	@25°C: >100GΩ or >1000ΩF whichever is less @200°C: >1GΩ or >10ΩF whichever is less
Dielectric withstanding voltage:	120%
Ageing rate:	0% per decade
Test parameters:	1KHz, 1.0 ±0.2 VRMS, 25°C



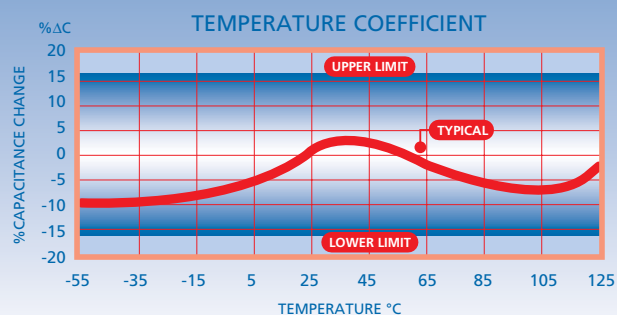
Y5V (Y) General Purpose

Operating temperature range:	-30°C to 85°C
Temperature coefficient:	+22% -82% ΔC Max.
Dissipation factor	>25V rating: 5.0% max ≤25V rating: 7.0% max
Insulation resistance @25%:	>10GΩ or >100ΩF whichever is less
Dielectric withstanding voltage	≤200V: 250% 250V: 150%
Ageing rate:	4.0% per decade
Test parameters:	1KHz, 1.0 ±0.2 VRMS, 25°C



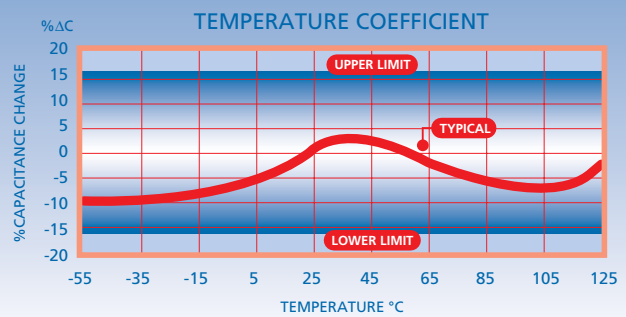
Z5U (Z) General Purpose

Operating temperature range:	+10°C to 85°C
Temperature coefficient:	+22% -56% ΔC Max.
Dissipation factor:	4.0% max @ 25°C
Insulation resistance @25%	>10GΩ or >100ΩF whichever is less
Dielectric withstanding voltage	≤200V: 250% 250V: 150%
Ageing rate:	4.0% per decade
Test parameters:	1KHz, 0.5 ±0.2 VRMS, 25°C



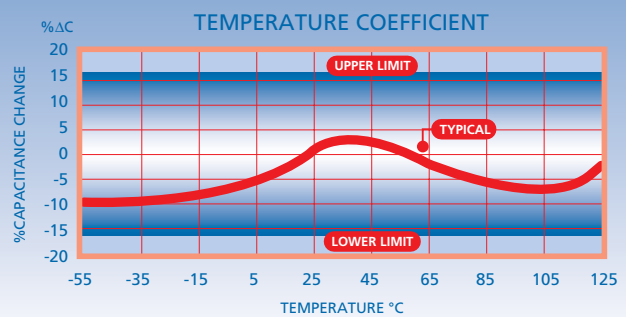
X7R (B) Stable and RoHS 2013 (RB) type

Operating temperature range:	-55°C to 125°C
Temperature coefficient :	±15% ΔC Max.
Dissipation factor	>25V rating: 2.5% max ≤25V rating: 3.5% max
Insulation resistance:	@25°C: >100GΩ or >1000ΩF whichever is less @125°C: >10GΩ or >100ΩF whichever is less
Dielectric withstanding voltage	≤200V: 250% 201-500V: 150% or 500V whichever is greater >500V: 120% or 750V whichever is greater
Ageing rate:	<2.0% per decade
Test parameters:	1KHz, 1.0 ±0.2 VRMS, 25°C



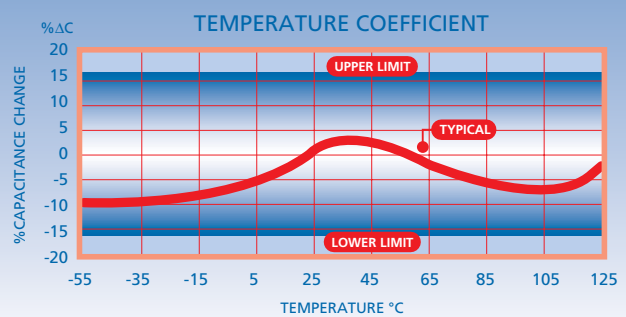
X7R (C) Stable Non Magnetic

Operating temperature range:	-55°C to 125°C
Temperature coefficient:	±15% ΔC Max.
Dissipation factor	>25V rating: 2.5% max ≤25V rating: 3.5% max
Insulation resistance:	@25°C: >100GΩ or >1000ΩF whichever is less @125°C: >10GΩ or >100ΩF whichever is less
Dielectric withstanding voltage	≤200V: 250% 201-500V: 150% or 500V whichever is greater >500V: 120% or 750V whichever is greater
Ageing rate:	<2.0% per decade
Test parameters:	1KHz, 1.0 ±0.2 VRMS, 25°C



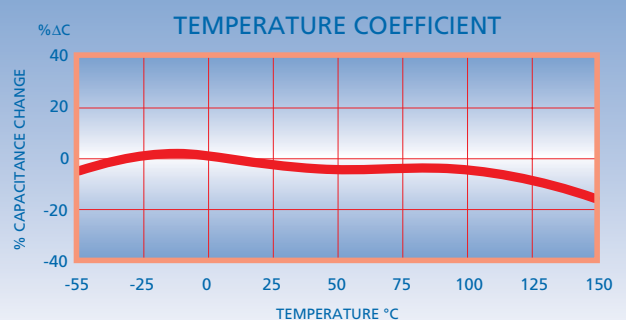
BX (X) Stable

Operating temperature range:	-55°C to 125°C
Temperature coefficient:	±15% ΔC Max.
Temp-voltage coefficient:	+15% -25% ΔC Max.
Dissipation factor	>25V rating: 2.5% max ≤25V rating: 3.5% max
Insulation resistance:	@25°C: >100GΩ or >1000ΩF whichever is less @125°C: >10GΩ or >100ΩF whichever is less
Dielectric withstanding voltage	≤200V: 250% 201-500V: 150% or 500V whichever is greater >500V: 120% or 750V whichever is greater
Ageing rate:	<2.0% per decade
Test parameters:	1KHz, 1.0 ±0.2 VRMS, 25°C



X8R (S) Stable

Operating temperature range:	-55°C to 150°C
Temp. coefficient ≤150°C:	±15% ΔC Max.
Dissipation factor	>25V rating: 2.5% max ≤25V rating: 3.5% max
Insulation resistance	@25°C: >100GΩ or >1000ΩF whichever is less @150°C: >10GΩ or >100ΩF whichever is less
Dielectric withstanding voltage	≤200V: 250% 201-500V: 150% or 500V whichever is greater >500V: 120% or 750V whichever is greater
Ageing rate:	<2.0% per decade
Test parameters:	1KHz, 1.0 ±0.2 VRMS, 25°C

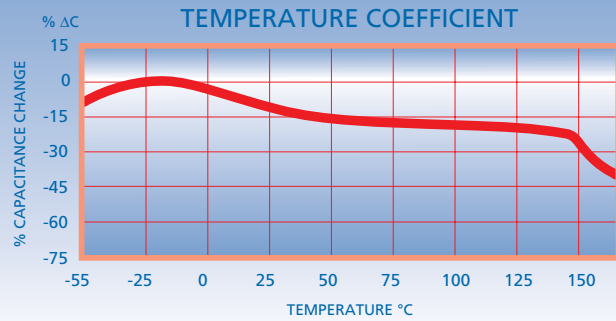


Dielectric Characteristics



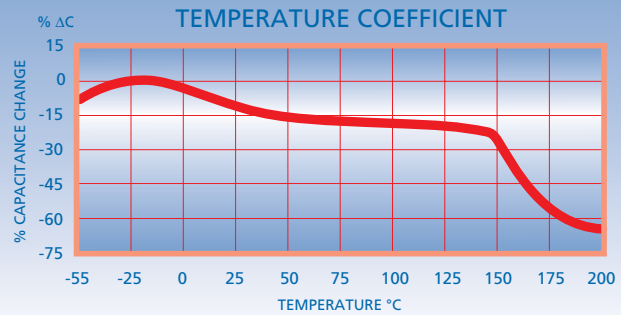
Class II (G) Stable High Temperature (up to 160°C)

Operating temperature range:	-55°C to 160°C
Temperature coefficient up to 160°C:	+15 -40% ΔC Max.
Dissipation factor @ 25°C:	2.5% Max.
Insulation resistance	@25°C: >100GΩ or >1000ΩF whichever is less @160°C: >1GΩ or >10ΩF whichever is less
Dielectric withstanding voltage	≤200V: 250% 201-500V: 150% or 500V whichever is greater >500V: 120% or 750V whichever is greater
Ageing rate:	< 2.0% per decade
Test parameters:	1KHz, 1.0 ±0.2 VRMS, 25°C



Class II (E) Stable High Temperature (up to 200°C)

Operating temperature range:	-55°C to 200°C
Temperature coefficient up to 200°C:	+15 -65% ΔC Max.
Dissipation factor @ 25°C:	2.5% Max.
Insulation resistance	@25°C: >100GΩ or >1000ΩF whichever is less @200°C: >1GΩ or >10ΩF whichever is less
Dielectric withstanding voltage	≤200V: 250% 201-500V: 150% or 500V whichever is greater >500V: 120% or 750V whichever is greater
Ageing rate:	< 2.0% per decade
Test parameters:	1KHz, 1.0 ±0.2 VRMS, 25°C



X5R (W) Stable

Operating temperature range:	-55°C to 85°C
Temperature coefficient up to 200°C:	±15% ΔC Max.
Dissipation factor @ 25°C:	5% Max.
Insulation resistance @25%:	>10GΩ or >500ΩF whichever is less
Dielectric withstanding voltage:	250%
Ageing rate:	< 5.0% per decade
Test parameters:	1KHz, 1.0 ±0.2 VRMS, 25°C Except: 22μF, 47μF & 100μF 120KHz, 0.5 ±0.1 VRMS, 25°C

